

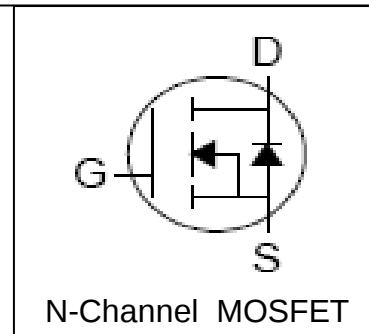
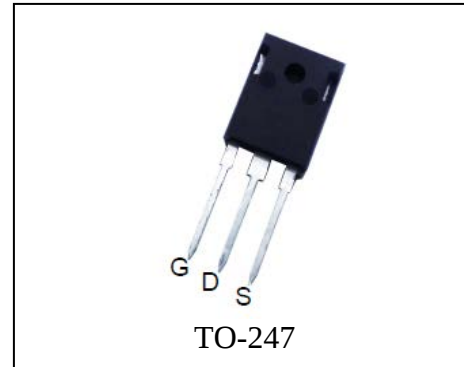
Features

- 80V/190A
 $R_{DS(ON)}=3.9m\Omega(Typ.) @ V_{GS}=10V$
- Avalanche Rated
- Reliable and Rugged
- Lead Free and Green Devices Available

Applications

- Automotive applications and a wide variety of other applications
- High Efficiency Synchronous in SMPS
- High Speed Power Switching

Pin Description



Absolute Maximum Ratings

Symbol	Parameter		Rating	Unit
Common Ratings (T _A =25°C Unless Otherwise Noted)				
V _{DSS}	Drain-Source Voltage		80	V
V _{GSS}	Gate-Source Voltage		±25	
T _J	Maximum Junction Temperature		175	°C
T _{STG}	Storage Temperature Range		-55 to 175	°C
I _S	Diode Continuous Forward Current	T _C =25°C	190 ^①	A
Mounted on Large Heat Sink				
I _{DP}	300μs Pulsed Drain Current Tested	T _C =25°C	700 ^②	A
I _D	Continue Drain Current	T _C =25°C	190 ^①	
		T _C =100°C	140 ^①	
P _D	Maximum Power Dissipation	T _C =25°C	326	W
		T _C =100°C	163	
R _{θJC}	Thermal Resistance -Junction to Case		0.46	°C/W
Drain-Source Avalanche Ratings				
E _{AS} ^③	Avalanche Energy ,Single Pulsed		1225	mJ

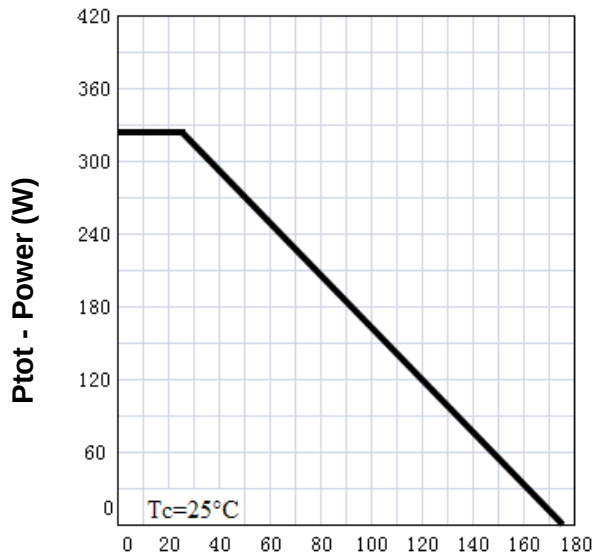
Electrical Characteristics ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

Symbol	Parameter	Test Condition	RU190N08Q			Unit
			Min.	Typ.	Max.	
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _{DS} =250μA	80			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 80V, V _{GS} =0V			1	μA
		T _j =85°C			30	
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =250μA	2	3	4	V
I _{GSS}	Gate Leakage Current	V _{GS} =±25V, V _{DS} =0V			±100	nA
R _{DS(ON)} ^④	Drain-Source On-state Resistance	V _{GS} = 10V, I _{DS} =40A		3.9	4.8	mΩ
Diode Characteristics						
V _{SD} ^④	Diode Forward Voltage	I _{SD} =40A, V _{GS} =0V			1.2	V
t _{rr}	Reverse Recovery Time	I _{SD} =40A, dI _{SD} /dt=100A/μs		68		ns
q _{rr}	Reverse Recovery Charge			130		nC
Dynamic Characteristics ^⑤						
R _G	Gate Resistance	V _{GS} =0V,V _{DS} =0V,F=1MHz		1.0		Ω
C _{iss}	Input Capacitance	V _{GS} =0V, V _{DS} = 30V, Frequency=1.0MHz		6800		pF
C _{oss}	Output Capacitance			1100		
C _{rss}	Reverse Transfer Capacitance			490		
t _{d(ON)}	Turn-on Delay Time	V _{DD} =35V, R _L =35Ω, I _{DS} = 1A, V _{GEN} = 10V, R _G =6Ω		38		ns
t _r	Turn-on Rise Time			22		
t _{d(OFF)}	Turn-off Delay Time			120		
t _f	Turn-off Fall Time			75		
Gate Charge Characteristics ^⑤						
Q _g	Total Gate Charge	V _{DS} =30V, V _{GS} = 10V, I _{DS} =40A		155		nC
Q _{gs}	Gate-Source Charge			45		
Q _{gd}	Gate-Drain Charge			48		

- Notes:
- ① Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 90A.
 - ② Pulse width limited by safe operating area.
 - ③ Limited by T_{Jmax} , $I_{AS}=50A$, $V_{DD}=48V$, $R_G=47\Omega$, Starting $T_J=25^\circ C$.
 - ④ Pulse test; Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
 - ⑤ Guaranteed by design, not subject to production testing.

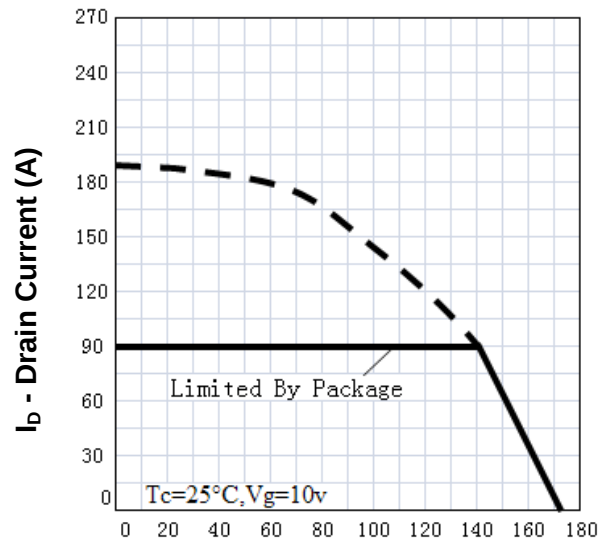
Typical Characteristics

Power Dissipation



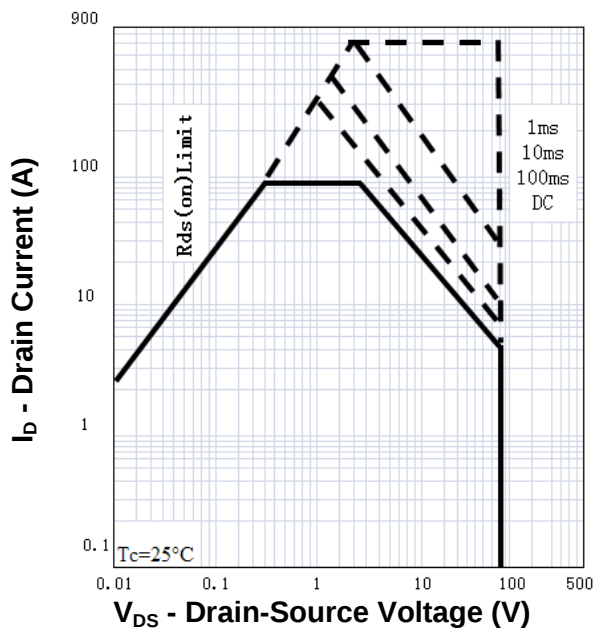
T_j - Junction Temperature ($^{\circ}\text{C}$)

Drain Current

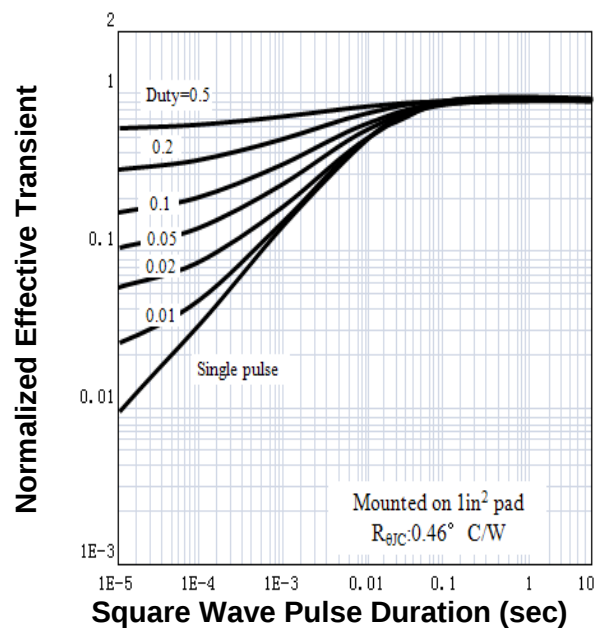


T_j - Junction Temperature ($^{\circ}\text{C}$)

Safe Operation Area

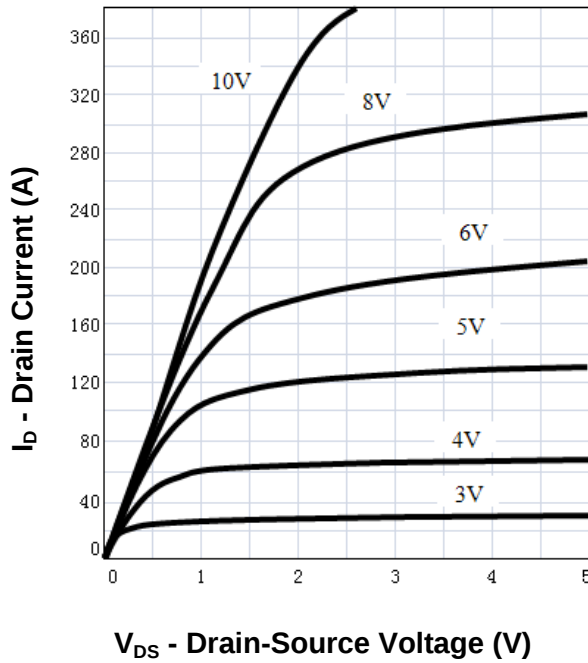


Thermal Transient Impedance

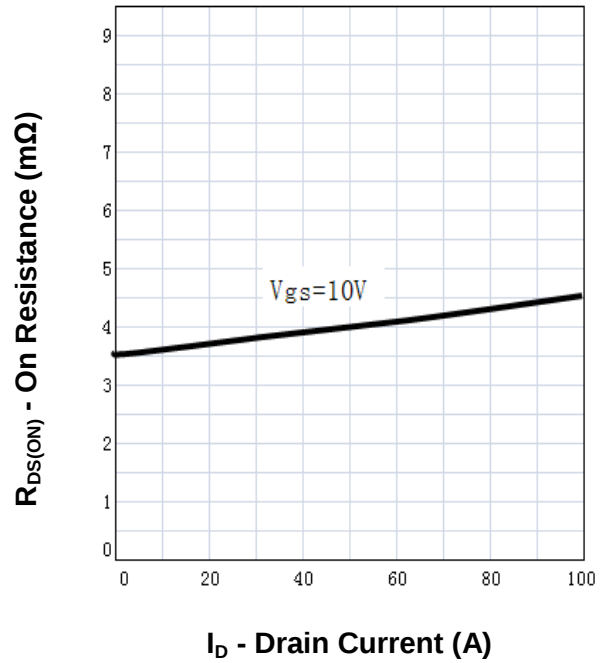


Typical Characteristics

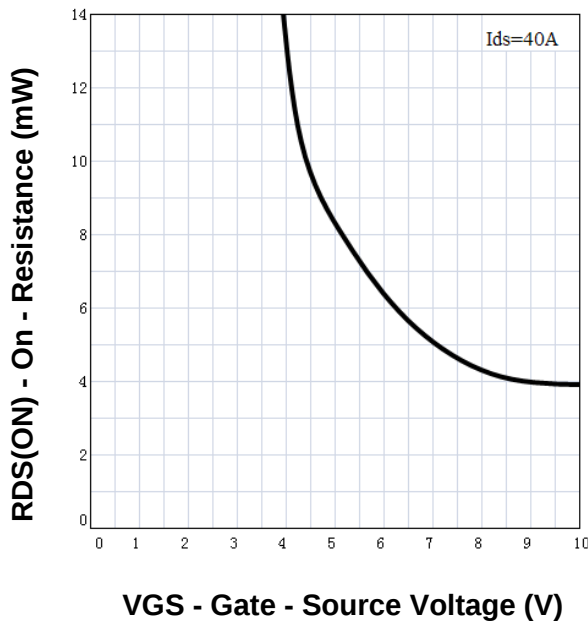
Output Characteristics



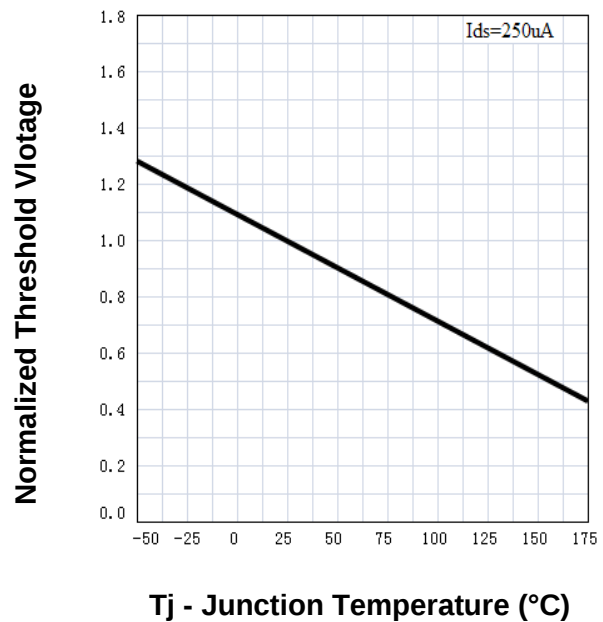
Drain-Source On Resistance



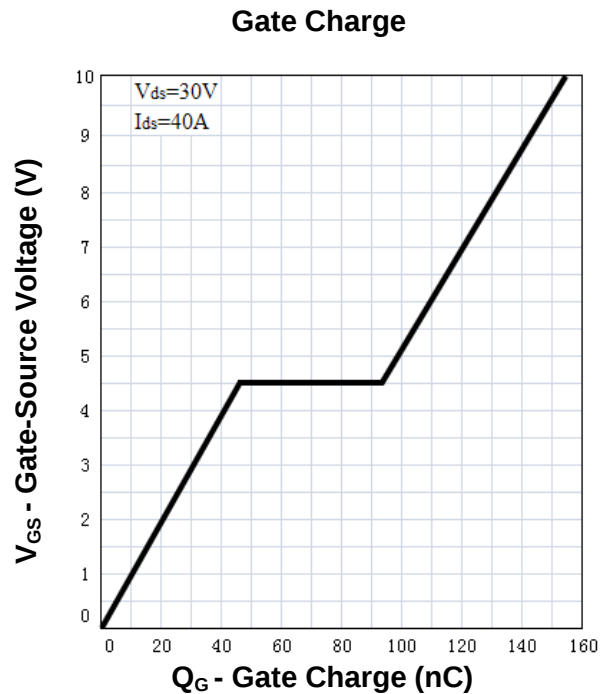
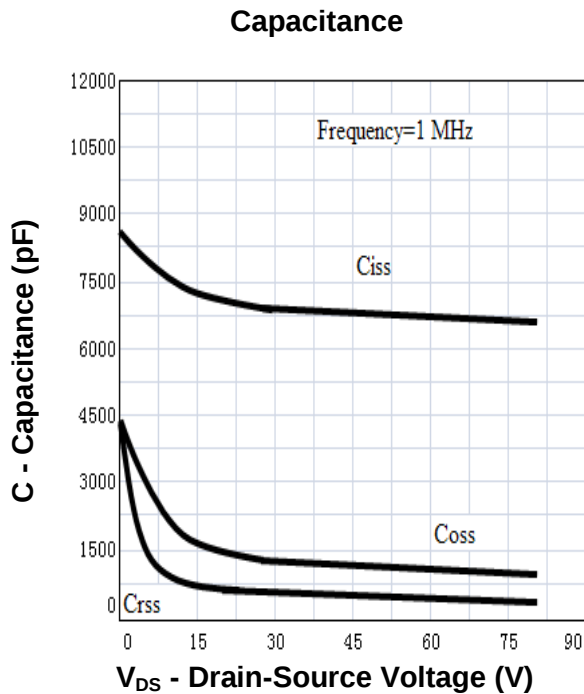
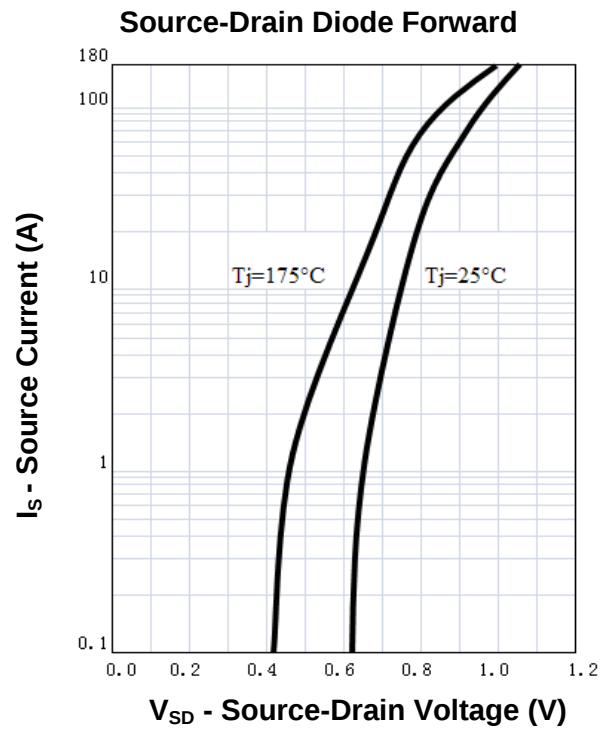
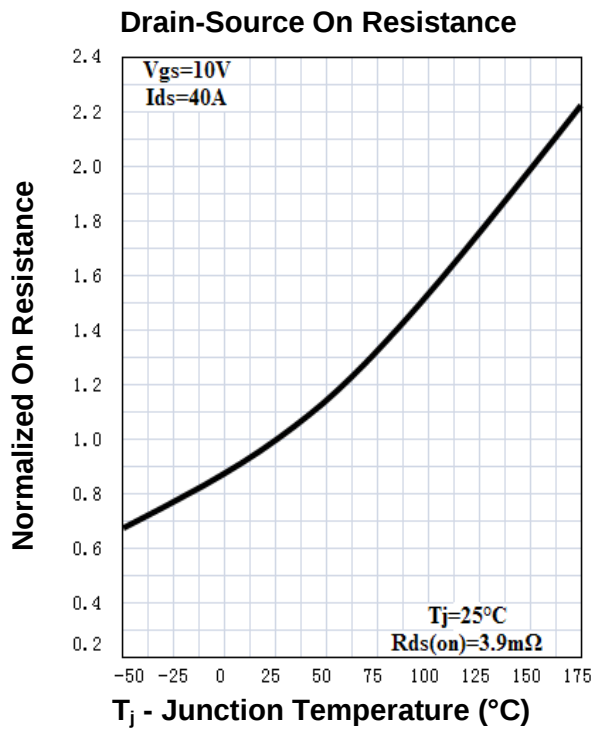
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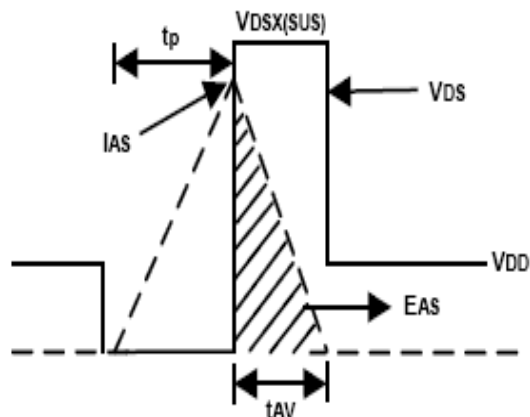
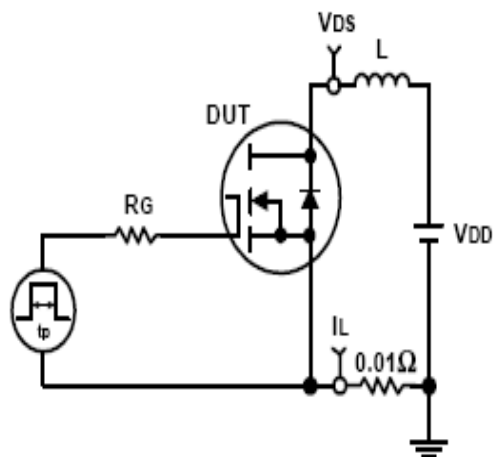
Gate Threshold Voltage



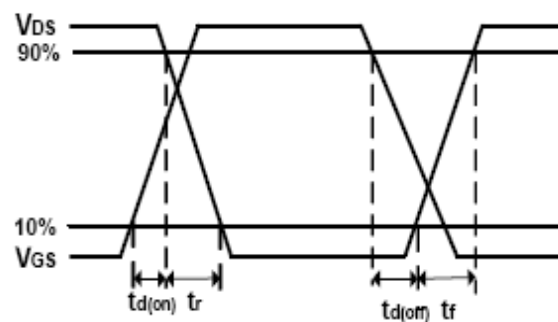
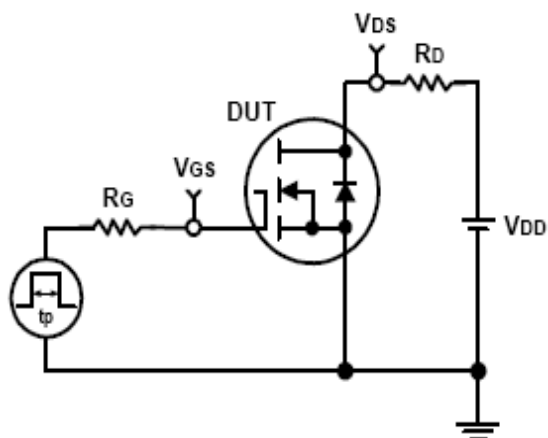
Typical Characteristics



Avalanche Test Circuit and Waveforms



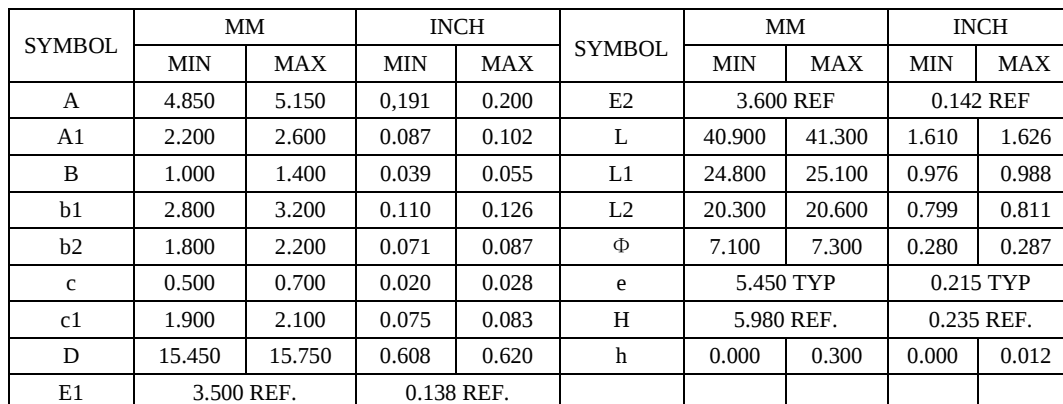
Switching Time Test Circuit and Waveforms



Ordering and Marking Information

Device	Marking	Package	Packaging	Quantity	Reel Size	Tape width
RU190N08Q	RU190N08Q	TO-247	Tube	30	-	-

TO-247



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